PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re: Kwang-hee Lee et al.

Serial No.: 10/801,208 Group Art Unit: 2811 Filed: March 16, 2004 Confirmation No.: 2034

For: METHODS OF MANUFACTURING SEMICONDUCTOR DEVICES HAVING A

RUTHENIUM LAYER USING VIA AUTOMATIC LAYER DEPOSITION AND

ASSOCIATED APPARATUS AND DEVICES

Date: January 10, 2005

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Sir:

Attached is Form PTO-1449 listing documents cited in the Korean Office Action for the corresponding Korean Application Number 2003-0019258. Each document listed on the attached PTO-1449 was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Statement. A copy of each document including the Korean Office Action, is enclosed.

No fee is believed due; however, the Commissioner is hereby authorized to charge any deficiency or credit any refund to Deposit Account No. 50-0220.

Respectfully submitted,

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Substitute form 1449A	/PTO	/		omplete if Known
		100 13 200 3	Application Number Filing Date	10/801,208
INFORMATION D	ISCLOSURE			March 16, 2004
STATEMENT BY	APPLICANT		First Named Inventor	Kwang-hee Lee et al.
		TRADPARKE	Group Art Unit	2829
(use as many sheets a	as necessary)	PADPART	Examiner Name	Unknown
Sheet 1	of	<u> 1 </u>	Attorney Docket Number	5649-1277

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U.S. PATENTS AND PATENT PUBLICATIONS						
Examiner Cite Initials*	Cite No.	U.S. Patent Document		Name of Patentee or Applicant of Cited	Date of Publication of Cited	
		Number	Number Kind Code (if known)	Document MM-DD-YYYY		
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				FOREIGN F	PATENT DOCUMENTS		
Initials*	C	Foreign Patent Document		cument	Name of Patentee or Applicant of Cited Document	Date of Publication	Т
	e N o.	Office	Number	Kind Code (if known)	Document	of Cited Document MM-DD-YYYY	
·	1	Korean Abstract	20040059775	,	Hynix Semiconductor Inc.	07/06/2004	
	2	Korean Abstract	20020074922	,	Samsung Electronics Co., Ltd.	10/04/2002	
	3	Korean Abstract	20020034715	Α	Hynix Semiconductor Inc.	12/18/2002	
			2				

OTHER NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T		
	4	Notice of Office Action, Korean Application No. 10-2003-0019258, September 30, 2004			
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Examiner Signature	Date Considered	
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